
2SA1960

Silicon NPN Epitaxial

HITACHI

ADE-208-392
1st. Edition

Application

- Wide band video output amplifier for color CRT monitor.
- High frequency high voltage amplifier.
- High speed power switching.
- Complementary pair with 2SC5225.

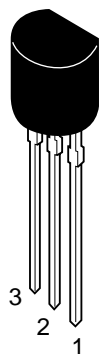
Features

- High voltage large current operation.
 $V_{CE0} = -80\text{ V}$, $I_C = -300\text{ mA}$
- High f_T .
 $f_T = 1.3\text{ GHz}$
- Small output capacitance.
 $C_{ob} = 2.9\text{ pF}$

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Outline

TO-92 (1)



1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings (Ta = 25°C)

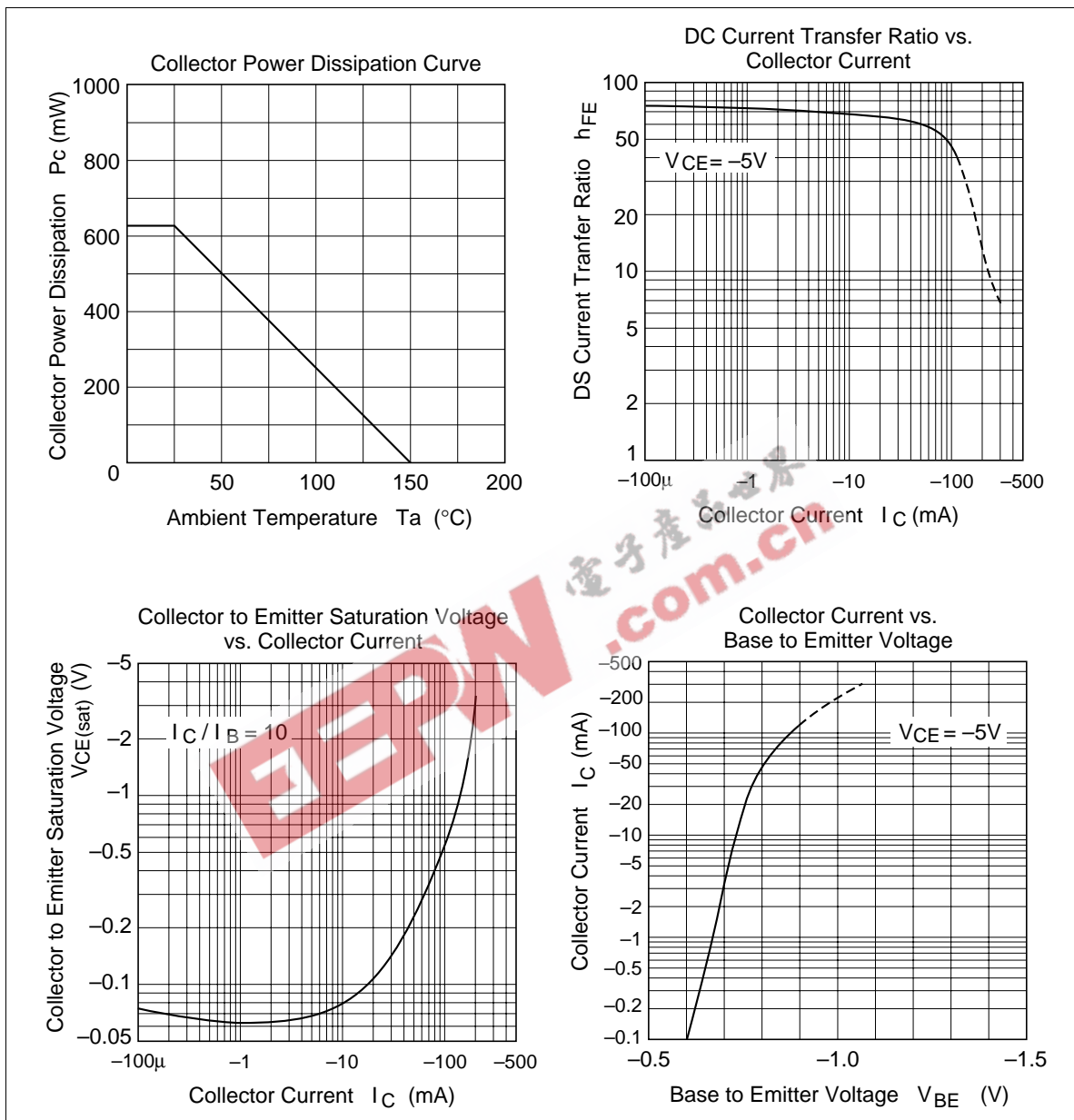
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	-80	V
Collector to emitter voltage	V_{CEO}	-80	V
Emitter to base voltage	V_{EBO}	-3	V
Collector current	I_C	-300	mA
Collector power dissipation	P_C	625	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

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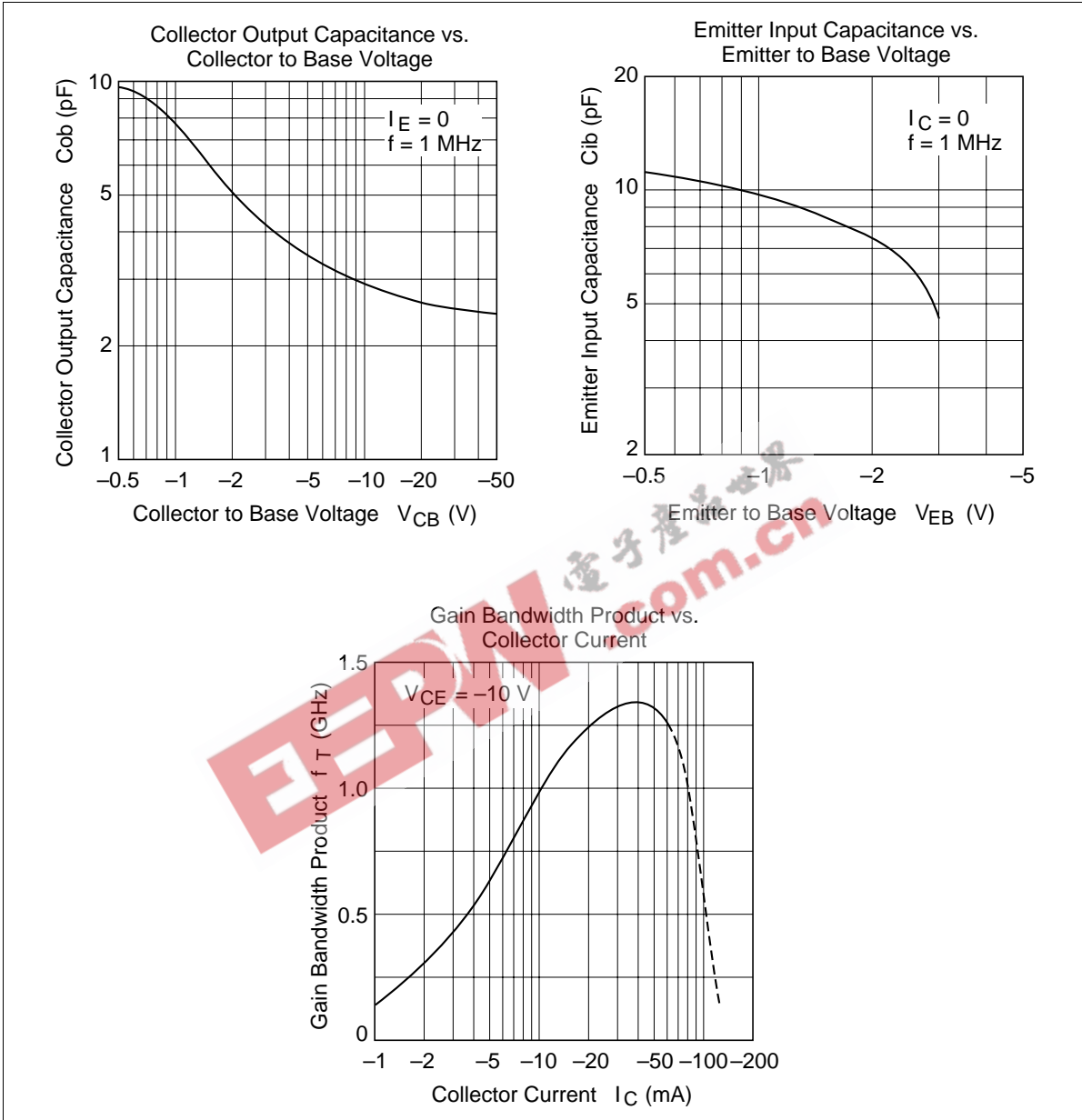
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-80	—	—	V	$I_C = -100 \mu\text{A}$ $I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-80	—	—	V	$I_C = -1 \text{ mA}$ $R_{BE} = \infty$
Collector to base cutoff current	I_{CBO}	—	—	-1.0	μA	$V_{CB} = -60 \text{ V}$ $I_E = 0$
Emitter to base cutoff current	I_{EBO}	—	—	-10	μA	$V_{EB} = -3 \text{ V}$ $I_C = 0$
DC current transfer ratio	h_{FE}	20	60	—		$V_{CE} = -5 \text{ V}$, $I_C = -50 \text{ mA}$ Pulse test
Gain bandwidth product	f_T	1.1	1.3	—	GHz	$V_{CE} = -10 \text{ V}$ $I_C = -50 \text{ mA}$
Emitter input capacitance	C_{ib}	—	14.5	18	pF	$V_{EB} = 0$, $I_C = 0$ $f = 1 \text{ MHz}$
Collector output capacitance	C_{ob}	—	2.9	4.0	pF	$V_{CB} = -10 \text{ V}$, $I_E = 0$ $f = 1 \text{ MHz}$

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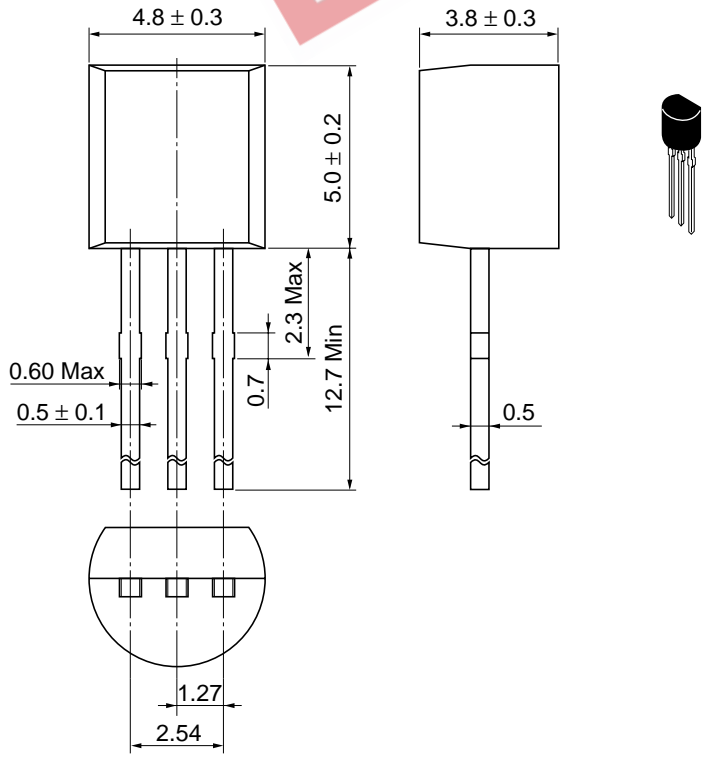


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Unit: mm



Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL North America : <http://semiconductor.hitachi.com/>
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For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe GmbH
Electronic components Group
Dornacher StraÙe 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 049318
Tel: 535-2100
Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building, No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX

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